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APPLICATION NO.		FILING DATE		FIRST NAMED INVENTOR		ATTORNEY DOCKET NO.	CONFIRMATION NO.
•	10/676,963	576,963 10/01/2003		Remigijus Gaska		SETI-0004	8123
	23550	7590	7590 05/20/2004		Г	EXAMINER	
	HOFFMAN 3 E-COMM		CK & D'ALESSA		FORDE, REMMON R		
	ALBANY,					ART UNIT	PAPER NUMBER
						2826	

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)						
Office Action Summary	10/676,963	GASKA ET AL.						
Office Action Summary	Examiner	Art Unit						
And the second s	Remmon R. Fordé	2826						
Th MAILING DATE of this communication apperent of the communica	ears on the cover sheet with the co	orrespondence address						
A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filled after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication. - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filled, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).								
Status								
1) Responsive to communication(s) filed on 01 Oc	tober 2003.							
2a) ☐ This action is FINAL. 2b) ☒ This action is non-final.								
3) Since this application is in condition for allowance except for formal matters, prosecution as to the ments is								
closed in accordance with the practice under Ex	x parte Quayle, 1935 C.D. 11, 45	3 O.G. 213.						
Disposition of Claims								
4)⊠ Claim(s) <u>1-20</u> is/are pending in the application.								
4a) Of the above claim(s) is/are withdraw	n from consideration.							
5)⊠ Claim(s) <u>12-20</u> is/are allowed.								
6)⊠ Claim(s) <u>1-11</u> is/are rejected.								
7) Claim(s) is/are objected to.								
8) Claim(s) are subject to restriction and/or	election requirement.							
Application Papers								
9)☐ The specification is objected to by the Examiner								
10) The drawing(s) filed on is/are: a) acce	pted or b)□ objected to by the E	xaminer.						
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).								
Réplacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).								
11) The oath or declaration is objected to by the Exa	aminer. Note the attached Office	Action or form PTO-152.						
Priority under 35 U.S.C. § 119								
12) Acknowledgment is made of a claim for foreign	onority under 35 U.S.C. § 119(a)-	-(d) or (f).						
a) All b) Some * c) None of:								
1. Certified copies of the priority documents								
2. Certified copies of the priority documents have been received in Application No 3. Copies of the certified copies of the priority documents have been received in this National Stage								
		o in this National Stage						
application from the International Bureau * See the attached detailed Office action for a list of								
See the attached detailed Office action for a list of	in the certified copies not received	3.						
		e *						
A44-1-1-1-1-1-1-1-1-1-1-1-1-1-1-1-1-1-1-								
Attachment(s) 1) Notice of References Cited (PTO-892)	A) The land of the contract of	PTO 412)						
2) Notice of Draftsperson's Patent Drawing Review (PTO-948)	4) 🔲 Interview Summary (Paper No(s)/Mail Dat							
3) 🔯 Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) 5) 🔲 Notice of Informal Patent Application (PTO-152)								
Paper No(s)/Mail Date <u>10/01/03</u> .	6) [_] Other:							

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DETAILED ACTION

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States

Claims 1-11 are rejected under 35 U.S.C. 102(b) as being anticipated by Ito et al..

Regarding claims 1, 3-5, 8-11, referencing Figure 8, Ito et al. discloses a semiconductor structure provided with a substrate (11); a first layer (31) formed above the substrate; and a textured nitride layer (35) formed on the first layer. (Abstract)

Regarding claim 2, referencing Figure 8, Ito et al. further discloses providing a metal layer (20) formed above the textured nitride layer. (Abstract)

Regarding claim 6, referencing Figure 8, Ito et al. further discloses that the semiconductor structure is used in a light-emitting device (30). (Abstract)

Regarding claim 7, referencing Figure 8, Ito et al. further discloses that the first layer (31) comprises a crystalline nitride layer (i.e. AIN). (Abstract)

Allowable Subject Matter

Claims 12-20 are allowed.

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The following is a statement of reasons for the indication of allowable subject matter:

Claim 12 recites a field effect transistor structure including the specific structural limitations of providing that a crystalline nitride layer formed above the active layer; and a textured nitride layer formed on the crystalline nitride layer, which is neither anticipated by nor obvious over the prior art of record. Likewise, claims 13-17 are also allowable as being dependent upon allowable claim 12.

Claim 18 recites a light emitting device structure including the specific structural limitations of providing a p-type crystalline nitride layer formed above the light emitting structure; and a textured nitride layer formed on the crystalline nitride layer, which is neither anticipated by nor obvious over the prior art of record. Likewise, claims 19 and 20 are also allowable as being dependent upon allowable claim 18.

Relevant Prior Art

The prior art made of record and not relied upon is considered pertinent to applicant's disclosure.

Dreifus et al., Byun et al. and Shibata et al. each disclose semiconductor devices implementing nitride-textured surfaces.

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Contact Information

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Remmon R. Fordé whose telephone number is (571) 272-1916. The examiner can normally be reached on Monday-Thursday (8:00-6:30).

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Nathan J. Flynn can be reached on (571) 272-1915. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

NATHAN J. FLYNN SUPERVISORY PATENT EXAMINER TECHNOLOGY CENTER 2800

Remmon R. Fordé

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